Triple 3-input NOR gate Rev. 4 — 5 June 2013

1. **General description**

The 74HC27; 74HCT27 is a triple 3-input NOR gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC27: CMOS level
 - For 74HCT27: TTL level
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Ordering information 3.

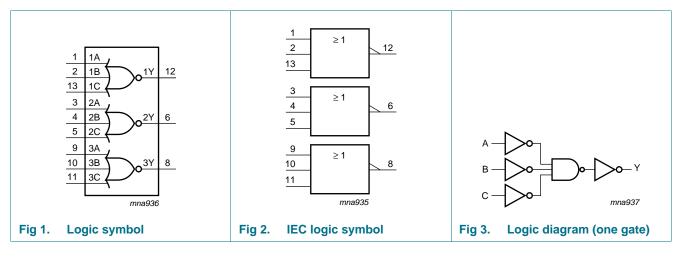
Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC27N	–40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1
74HCT27N				
74HC27D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HCT27D				
74HC27DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body width	SOT337-1
74HCT27DB			5.3 mm	
74HC27PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body	SOT402-1
74HCT27PW			width 4.4 mm	
74HC27BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin	SOT762-1
74HCT27BQ			quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm	



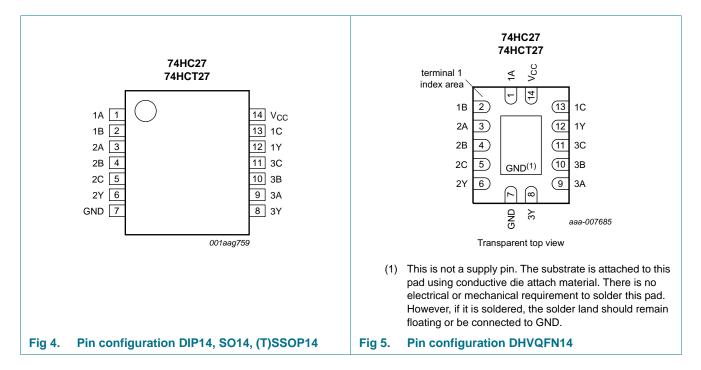
Triple 3-input NOR gate

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. P	in description	
Symbol	Pin	Description
1A, 2A, 3A	1, 3, 9	data input
1B, 2B, 3B	2, 4, 10	data input
1C, 2C, 3C	13, 5, 11	data input
1Y, 2Y, 3Y	12, 6, 8	data output
GND	7	ground (0 V)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table^[1]

Inputs			Outputs
nA	nB	nC	nY
L	L	L	Н
X	Х	Н	L
X	Н	Х	L
Н	Х	Х	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}}$ + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2]		
	DIP14 package		-	750	mW
	SO14, (T)SSOP14 and DHVQFN14 packages		-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP14 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

For SO14 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 $^\circ$ C.

For DHVQFN14 packages: Ptot derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC27		74HCT27			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics type 74HC27; 74HCT27

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit
			Min Typ Max		Min	Max	Min	Max		
74HC27										
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
	V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V	
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V V V V V V V V V V V V V V V V V V V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{ОН}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = –20 $\mu A; V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I_{O} = –20 $\mu\text{A};V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I_{O} = –20 $\mu A;$ V_{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current		-	-	2.0	-	20	-	40	μΑ

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit
			Min	Тур	Max	Min	Max	Min	Мах	
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT2	7									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH} HIGH-level		$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V	
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL} LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$									
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		l _O = 4.0 mA	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	2.0	-	20	-	40	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V; $I_O = 0 A$								
		nA, nB or nC inputs	-	150	540	-	675	-	735	μΑ
CI	input capacitance		-	3.5	-	-	-	-	-	pF

Table 6. Static characteristics type 74HC27; 74HCT27 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

10. Dynamic characteristics

Table 7. Dynamic characteristics type 74HC27; 74HCT27

GND = 0 V; for load circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C to	o +125 ℃	Unit
			-	Min	Тур	Max	Max (85 °C)	Max (125 °C)	
74HC27	,						1		
t _{pd}	propagation delay	nA, nB, nC to nY; see Figure 6	<u>[1]</u>						
		$V_{CC} = 2.0 V$		-	28	90	115	135	ns
		$V_{CC} = 4.5 V$		-	10	18	23	27	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	8	-	-	-	ns
		$V_{CC} = 6.0 V$		-	8	15	20	23	ns
t _t	transition time	see <u>Figure 6</u>	[2]						
		$V_{CC} = 2.0 V$		-	19	75	95	110	ns
		$V_{CC} = 4.5 V$		-	7	15	19	22	ns
		$V_{CC} = 6.0 V$		-	6	13	16	19	ns
C _{PD}	power dissipation capacitance	per package; $V_1 = GND$ to V_{CC}	<u>[3]</u>	-	24	-	-	-	pF
74HCT2	27								
t _{pd}	propagation delay	nA, nB, nC to nY; see <u>Figure 6</u>	<u>[1]</u>						
		$V_{CC} = 4.5 V$		-	12	21	26	32	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	10	-	-	-	ns
tt	transition time	V_{CC} = 4.5 V; see <u>Figure 6</u>	[2]	-	7	15	19	22	ns
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} – 1.5 V	<u>[3]</u>	-	30	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

 $\label{eq:ttime_time} [2] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_{\mathsf{i}} \times \mathsf{N} + \Sigma \; (\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_{\mathsf{o}}) \; \mathsf{where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 \sum (C_L × V_{CC}² × f_o) = sum of outputs.



11. Waveforms

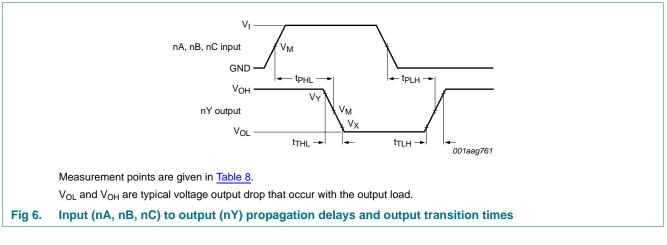


Table 8. Measurement points

Туре	Input	Output			
	V _M	V _M	V _X	V _Y	
74HC27	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}	
74HCT27	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}	

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74HC27; 74HCT27

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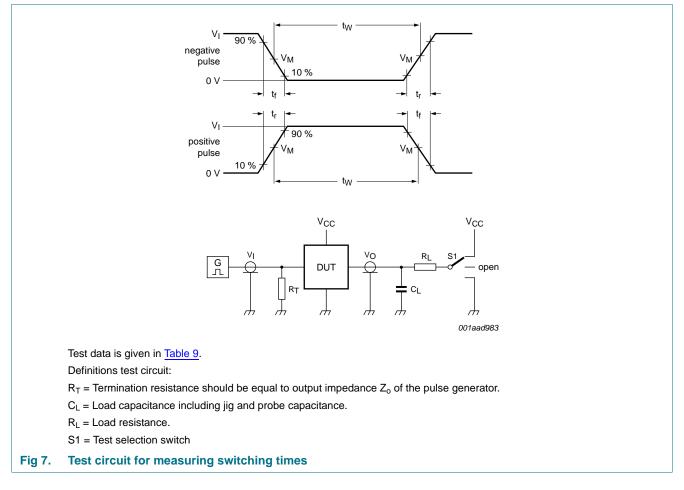


Table 9. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}
74HC27	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT27	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

Triple 3-input NOR gate

12. Package outline

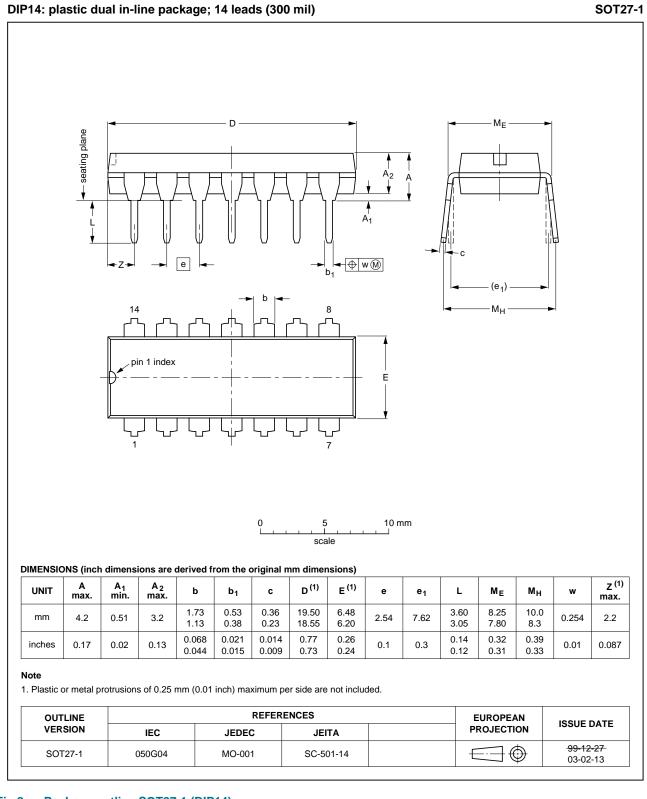
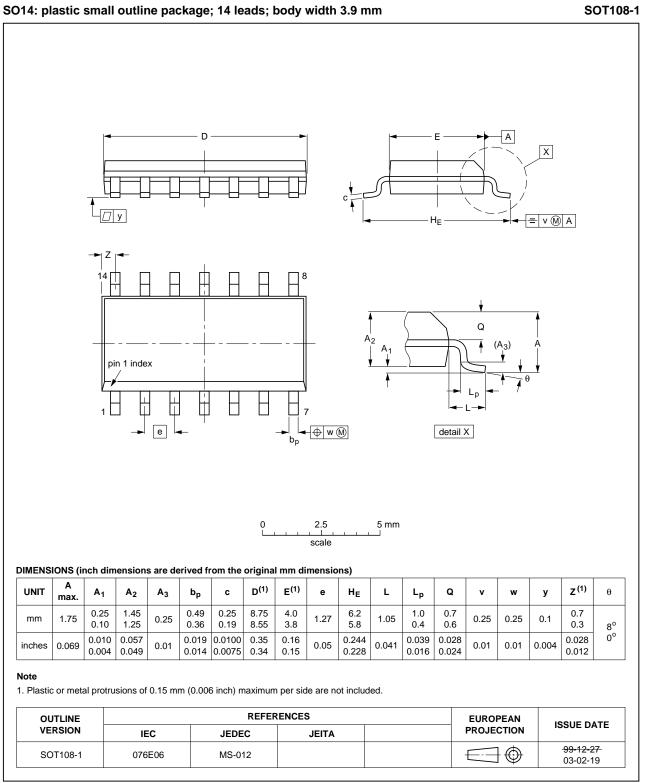


Fig 8. Package outline SOT27-1 (DIP14)

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Package outline SOT108-1 (SO14) Fig 9.

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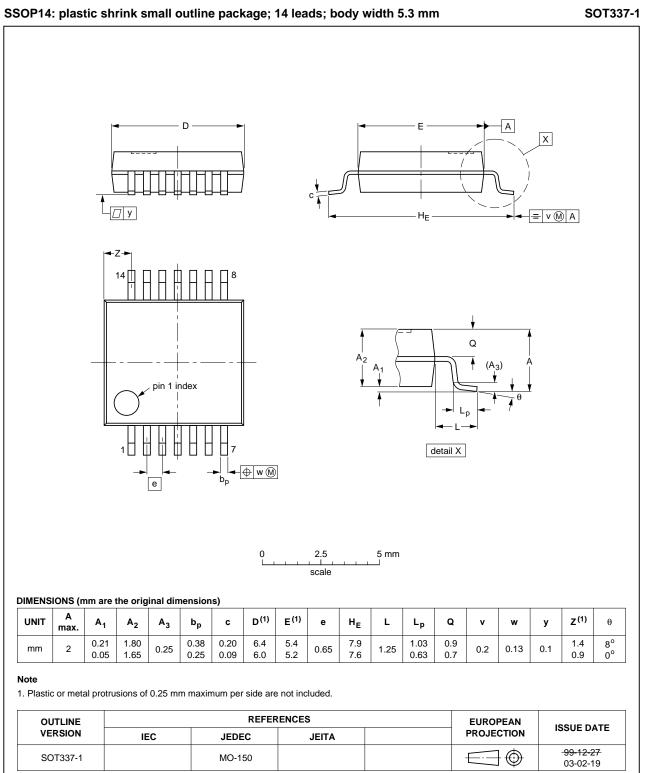


Fig 10. Package outline SOT337-1 (SSOP14)

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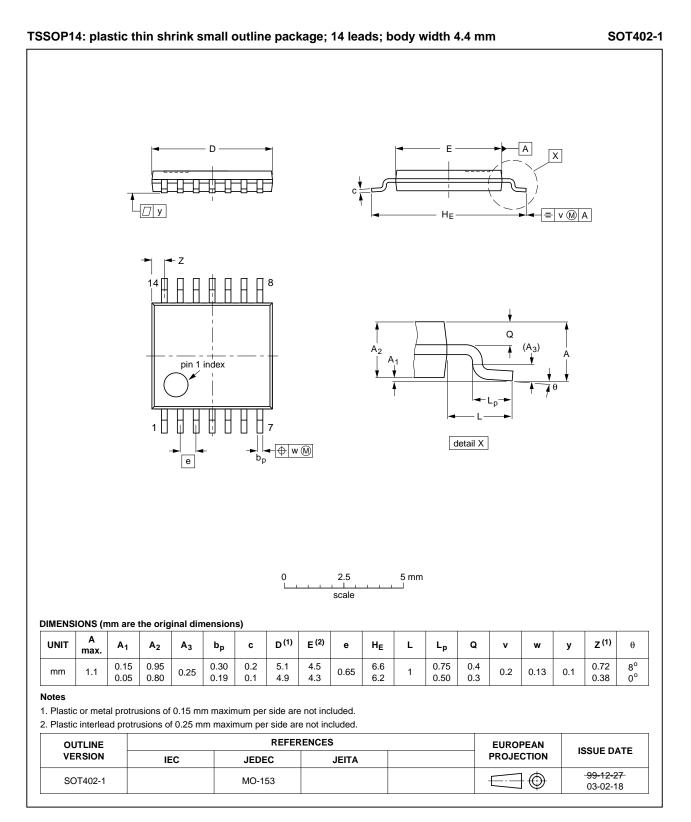
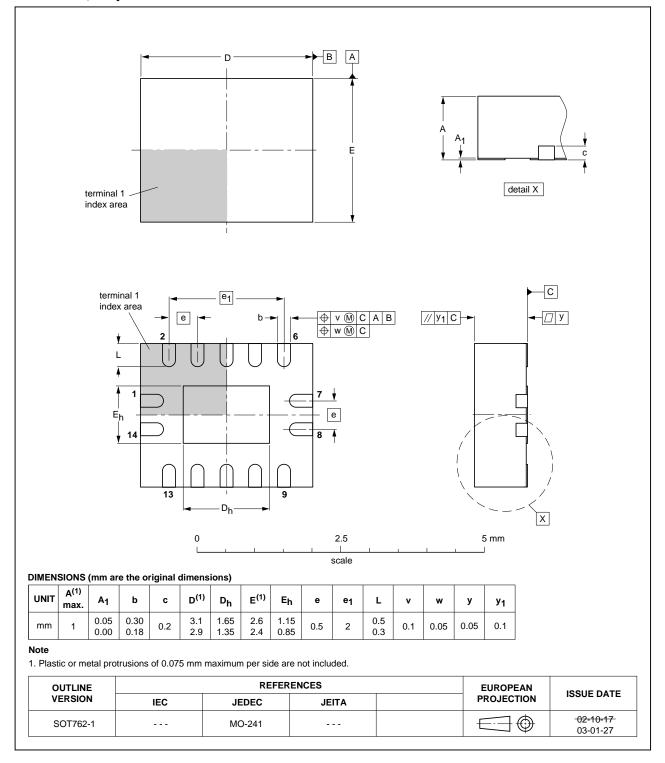


Fig 11. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

Fig 12. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 10. A	bbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT27 v.4	20130605	Product data sheet	-	74HC_HCT27 v.3
Modifications:		of this data sheet has beer of NXP Semiconductors.	n redesigned to co	mply with the new identity
	 Legal texts 	have been adapted to the	new company nam	e where appropriate.
74HC_HCT27 v.3	20080107	Product data sheet	-	74HC_HCT27_CNV v.2
74HC_HCT27_CNV v.2	19970828	Product specification	-	-

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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74HC HCT27

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